

Product data sheet

1. General description

Planar passivated very sensitive gate four quadrant triac in a TO92 plastic package intended for use in applications requiring enhanced noise immunity and direct interfacing to logic ICs and low power gate drivers.

2. Features and benefits

- Direct interfacing to logic level ICs
- Enhanced current surge capability
- · Enhanced noise immunity
- High blocking voltage capability
- · Planar passivated for voltage ruggedness and reliability
- Triggering in all four quadrants
- Very sensitive gate

3. Applications

- General purpose low power motor control
- Home appliances
- Industrial process control
- Low power AC Fan controllers

4. Quick reference data

	uick reference data				_		
Symbol	Parameter	Conditions		Min	Тур	Max	Unit
Absolute	maximum rating						
V_{DRM}	repetitive peak off-state voltage		-	-	-	800	V
I _{T(RMS)}	RMS on-state currentfull sine wave; $T_{lead} \le 45 \text{ °C}$;Fig. 1; Fig. 2; Fig. 3		-	-	-	1	A
I _{TSM}	non-repetitive peak on- state current	full sine wave; T _{j(init)} = 25 °C; t _p = 20 ms; <u>Fig. 4; Fig. 5</u>	-	-	-	12.5	A
		full sine wave; $T_{j(init)}$ = 25 °C; t_p = 16.7 ms	-	-	-	13.8	А
Tj	junction temperature		-	-	-	125	°C
Symbol	Parameter	Conditions		Min	Тур	Max	Unit
Static ch	aracteristics						
I _{GT}	gate trigger current	V _D = 12 V; I _T = 0.1 A; T2+ G+; T _j = 25 °C; <u>Fig. 7</u>	(0.3	-	5	mA
		$V_{D} = 12 \text{ V}; \text{ I}_{T} = 0.1 \text{ A}; \text{ T2+ G-};$ T _j = 25 °C; <u>Fig. 7</u>	(0.3	-	5	mA
		V _D = 12 V; I _T = 0.1 A; T2- G-; T _j = 25 °C; <u>Fig. 7</u>	(0.3	-	5	mA
		V _D = 12 V; I _T = 0.1 A; T2- G+; T _j = 25 °C; <u>Fig. 7</u>		0.3	-	7	mA
I _H	holding current	V _D = 12 V; T _j = 25 °C; <u>Fig. 9</u>	-	-	-	10	mA
V _T	on-state voltage	I _τ = 1 A; T _i = 25 °C; <u>Fig. 10</u>		-	1.3	1.6	V

4Q Triac

Z0107NA0

Symbol	Parameter	Conditions		Min	Тур	Max	Unit
Dynamic characteristics							
dV _D /dt	rate of rise of off-state voltage	$V_{DM} = 536 \text{ V}; \text{ T}_{\text{j}} = 110 \text{ °C}; (V_{DM} = 67\% \text{ of } V_{DRM}); exponential waveform; gate open circuit; Fig. 12$		100	-	-	V/µs
dV _{com} /dt	rate of change of commutating voltage	V_{D} = 400 V; T _j = 110 °C; dI _{com} /dt = 0.44 A/ms; gate open circuit		1	-	-	V/µs

5. Pinning information

Table 2. P	Fable 2. Pinning information									
Pin	Symbol	Description	Simplified outline	Graphic symbol						
1	T2	main terminal 2		Ν						
2	G	gate								
3	T1	main terminal 1	∬ ∬ ∬ ∬ ∬ ∬ TO-92 (SOT54)	sym051						

6. Ordering information

Table 3. Ordering information									
Type number	Package Name	Orderable part number	Packing method	Small packing quantity	Package version	Package issue date			
Z0107NA0	TO92	Z0107NA0,412	Bulk	1000	SOT54	14-Nov-2013			
Z0107NA0	TO92	Z0107NA0QP	Reel	2000	SOT54 wide pitch	14-Nov-2013			
Z0107NA0/L02	ТО92	Z0107NA0/L02EP	Bulk	500	SOT54	14-Nov-2013			

7. Marking

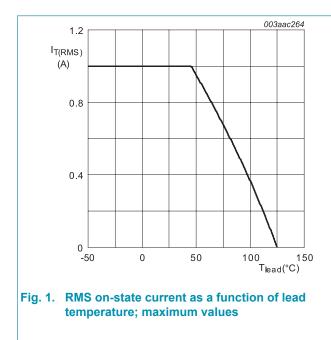
Table 4. Marking codes	
Type number	Marking codes
Z0107NA0	107NA0

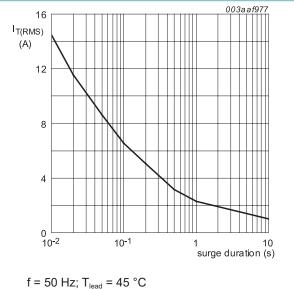
8. Limiting values

Table 5. Limiting values

In accordance with the Absolute Maximum Rating System (IEC 60134).

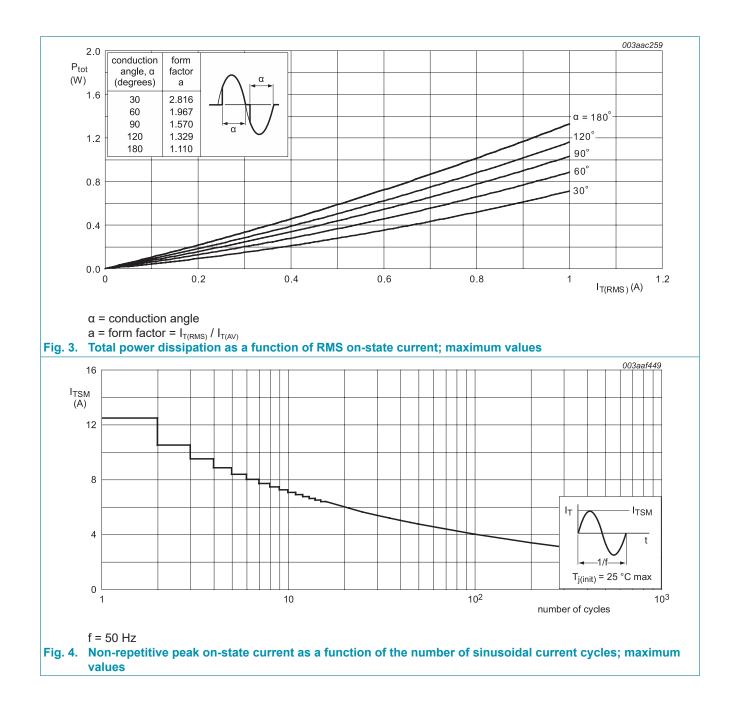
Symbol	Parameter	Conditions	Min	Max	Unit
V _{DRM}	repetitive peak off-state voltage		-	800	V
I _{T(RMS)}	RMS on-state current	full sine wave; T _{lead} ≤ 45 °C; <u>Fig. 1; Fig. 2</u> ; <u>Fig. 3</u>	-	1	A
I _{TSM}	non-repetitive peak on- state current	full sine wave; T _{j(init)} = 25 °C; t _p = 20 ms; Fig. 4; Fig. 5	-	12.5	A
		full sine wave; $T_{j(init)}$ = 25 °C; t_p = 16.7 ms	-	13.8	А
l ² t	I ² t for fusing	t _p = 10 ms; SIN	-	0.78	A ² s
dl _⊤ /dt	rate of rise of on-state current	I _G = 20 mA; T2+ G+	-	50	A/µs
		I _G = 20 mA; T2+ G-	-	50	A/µs
		I _G = 20 mA; T2- G-	-	50	A/µs
		I _G = 20 mA; T2- G+	-	20	A/µs
I _{GM}	peak gate current		-	1	А
P _{GM}	peak gate power		-	2	W
P _{G(AV)}	average gate power	over any 20 ms period	-	0.1	W
T _{stg}	storage temperature		-40	150	°C
T _i	junction temperature		-	125	°C





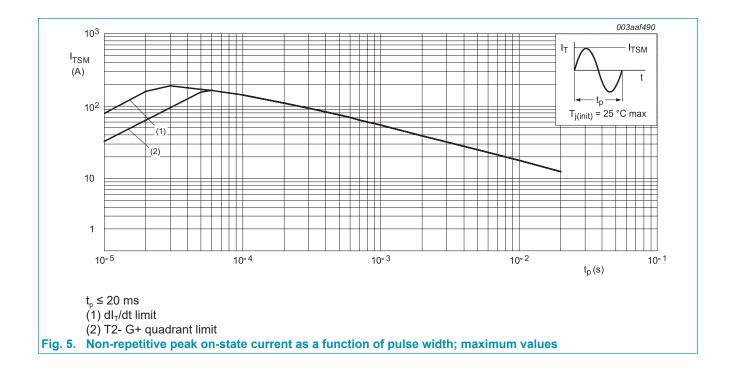


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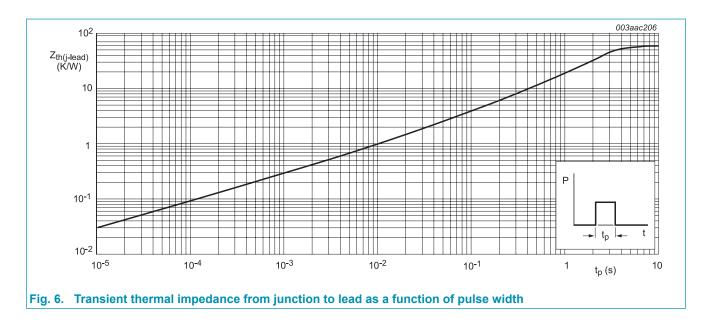
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9. Thermal characteristics

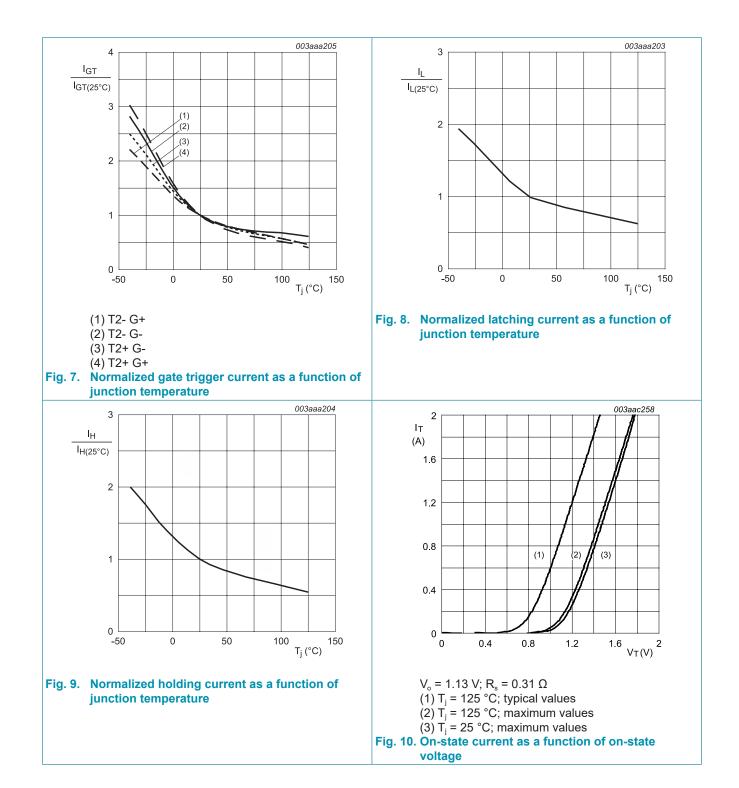
Table 6. Th	able 6. Thermal characteristics							
Symbol	Parameter	Conditions		Min	Тур	Max	Unit	
$R_{th(j-lead)}$	thermal resistance from junction to lead	full cycle; <u>Fig. 6</u>		-	-	60	K/W	
$R_{th(j\text{-}a)}$	thermal resistance from junction to ambient free air	full cycle; printed circuit board: lead length = 4 mm		-	150	-	K/W	



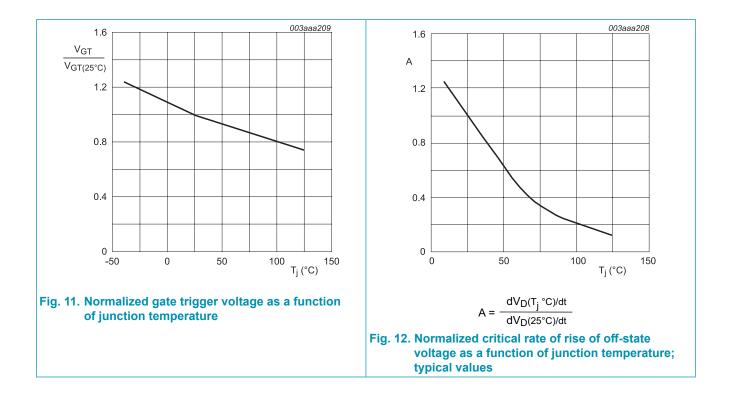
10. Characteristics

Symbol	Parameter	Conditions	Min	Тур	Max	Unit
Static cha	racteristics	· · · · · · · · · · · · · · · · · · ·			•	
Ι _{GT}	gate trigger current	$V_{D} = 12 \text{ V}; \text{ I}_{T} = 0.1 \text{ A}; \text{ T2+ G+};$ $T_{j} = 25 ^{\circ}\text{C}; \text{ Fig. 7}$	0.3	-	5	mA
		$V_{D} = 12 \text{ V}; \text{ I}_{T} = 0.1 \text{ A}; \text{ T2+ G-};$ $T_{j} = 25 \text{ °C}; \text{ Fig. 7}$	0.3	-	5	mA
		$V_{D} = 12 \text{ V}; \text{ I}_{T} = 0.1 \text{ A}; \text{ T2- G-};$ $T_{j} = 25 ^{\circ}\text{C}; \text{ Fig. 7}$	0.3	-	5	mA
		$V_{D} = 12 \text{ V}; \text{ I}_{T} = 0.1 \text{ A}; \text{ T2- G+};$ $T_{j} = 25 \text{ °C}; \text{ Fig. 7}$	0.3	-	7	mA
IL	latching current	$V_{D} = 12 \text{ V}; \text{ I}_{G} = 0.1 \text{ A}; \text{ T2+ G+};$ $\text{T}_{j} = 25 ^{\circ}\text{C}; \text{ Fig. 8}$	-	-	10	mA
		V_{D} = 12 V; I_{G} = 0.1 A; T2+ G-; T _j = 25 °C; Fig. 8	-	-	25	mA
		V_{D} = 12 V; I_{G} = 0.1 A; T2- G-; T _j = 25 °C; Fig. 8	-	-	10	mA
		V_{D} = 12 V; I_{G} = 0.1 A; T2- G+; T _j = 25 °C; Fig. 8	-	-	10	mA
I _H	holding current	V _D = 12 V; T _j = 25 °C; <u>Fig. 9</u>	-	-	10	mA
V _T	on-state voltage	I _T = 1 A; T _j = 25 °C; <u>Fig. 10</u>	-	1.3	1.6	V
V _{GT}	gate trigger voltage	$V_{D} = 12 \text{ V}; \text{ I}_{T} = 0.1 \text{ A}; \text{ T}_{j} = 25 \text{ °C};$ Fig. 11	-	-	1	V
		V _D = 800 V; I _T = 0.1 A; T _j = 125 °C	0.2	-	-	V
I _D	off-state current	V _D = 800 V; T _j = 125 °C	-	-	0.5	mA
Dynamic	characteristics	· · ·	I			
dV _D /dt	rate of rise of off-state voltage	V_{DM} = 536 V; T _j = 110 °C; (V_{DM} = 67% of V_{DRM}); exponential waveform; gate open circuit; Fig. 12	100	-	-	V/µs
dV _{com} /dt	rate of change of commutating voltage	$V_D = 400 \text{ V}; \text{ T}_j = 110 \text{ °C}; \text{ dI}_{com}/\text{dt} = 0.44$ A/ms; gate open circuit	1	-	-	V/µs

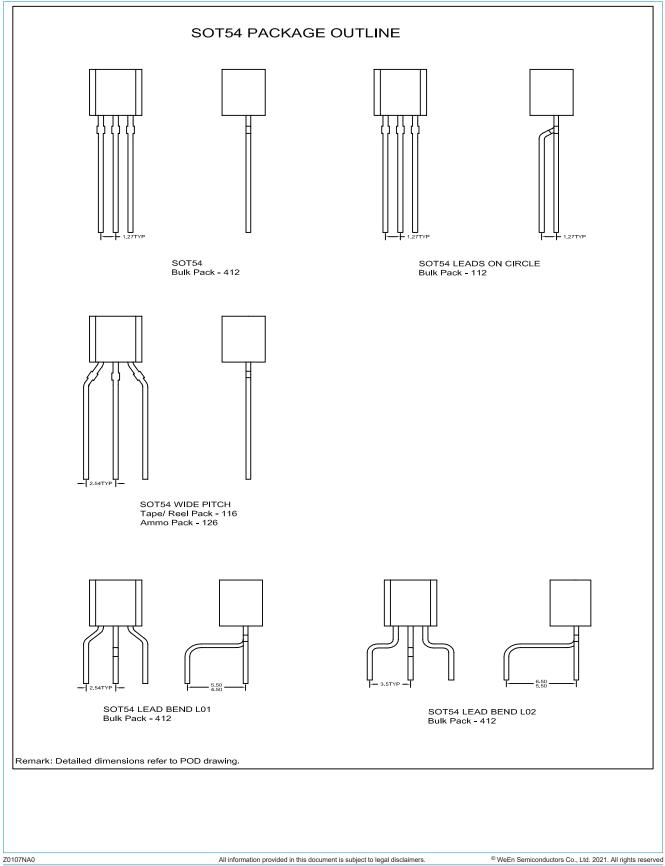
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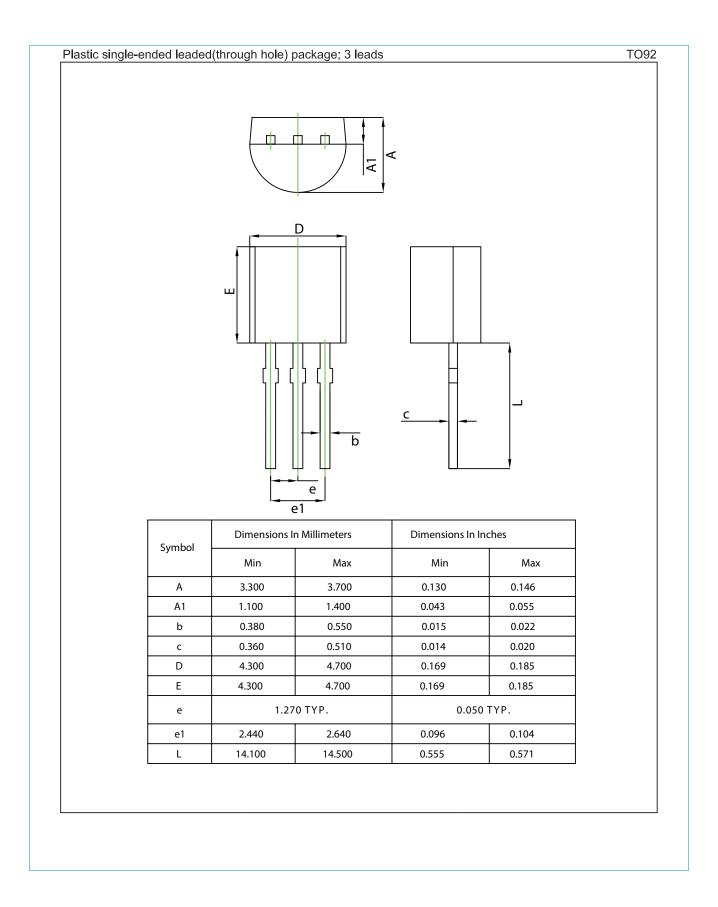






11. Package outline





12. Legal information

Data sheet status

Document status [1][2]	Product status [3]	Definition
Objective [short] data sheet	Development	This document contains data from the objective specification for product development.
Preliminary [short] data sheet	Qualification	This document contains data from the preliminary specification.
Product [short] data sheet	Production	This document contains the product specification.

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